Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT186A "full pack" plastic package intended for use in general purpose bidirectional switching and phase control applications.

2. Features and benefits

- High blocking voltage capability
- Isolated package
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V_{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | - | 65 | Α |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 88$ °C; Fig. 1; Fig. 2; Fig. 3 | - | - | 6 | Α |
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2+ G+;$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 5 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G-;$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 8 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2- \text{ G-;}$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 11 | 35 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2- \text{ G+;}$ $T_j = 25 \text{ °C; } Fig. 7$ | - | 30 | 70 | mA |





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5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------------------|--------------------|----------------|
| 1 | T1 | main terminal 1 | mb | T2——T1 |
| 2 | T2 | main terminal 2 | | Sym051 |
| 3 | G | gate | | y |
| mb | n.c. | mounting base; isolated | | |
| | | | | |
| | | | TO-220F (SOT186A) | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | | | | |
|-------------|---------|---|---------|--|--|--|--|--|--|
| | Name | Description | Version | | | | | | |
| BT236X-600 | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | | | | |

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V_{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 88$ °C; Fig. 1; Fig. 2; Fig. 3 | - | 6 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5 | - | 65 | A |
| | | full sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 16.7 \text{ms}$ | - | 71 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 21 | A ² s |
| dl _T /dt | rate of rise of on-state current | I _G = 70 mA; T2+ G+ | - | 50 | A/µs |
| | | I _G = 70 mA; T2+ G- | - | 50 | A/µs |
| | | I _G = 140 mA; T2- G+ | - | 10 | A/µs |
| | | I _G = 70 mA; T2- G- | - | 50 | A/µs |
| I _{GM} | peak gate current | | - | 2 | Α |
| P_{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

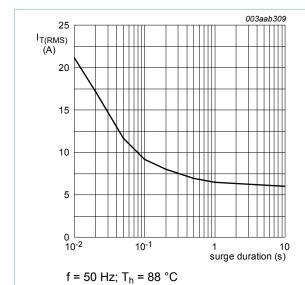


Fig. 1. RMS on-state current as a function of surge duration; maximum values

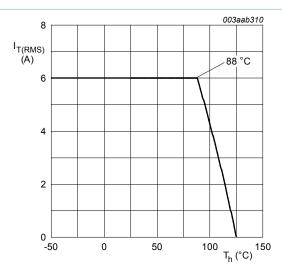


Fig. 2. RMS on-state current as a function of heatsink temperature; maximum values

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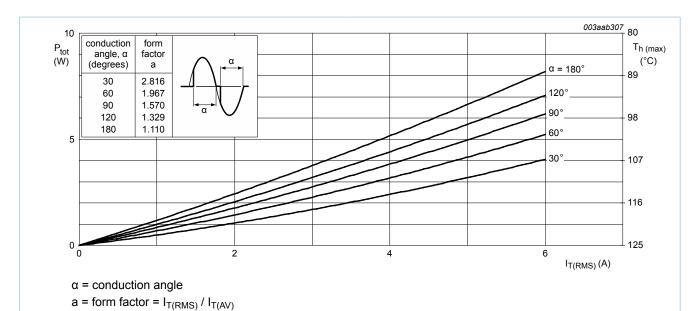


Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values

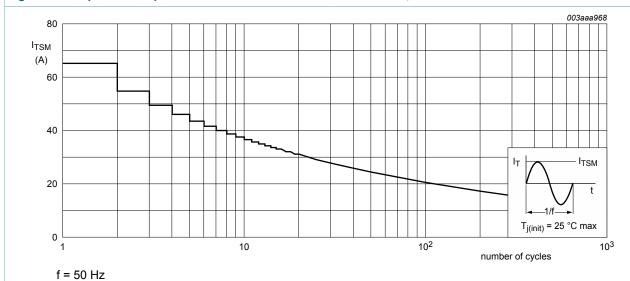
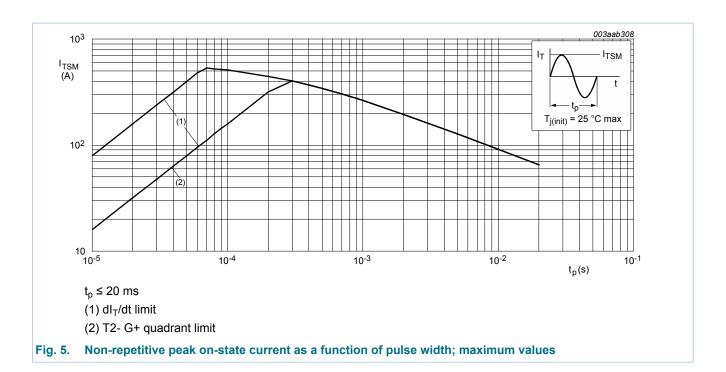


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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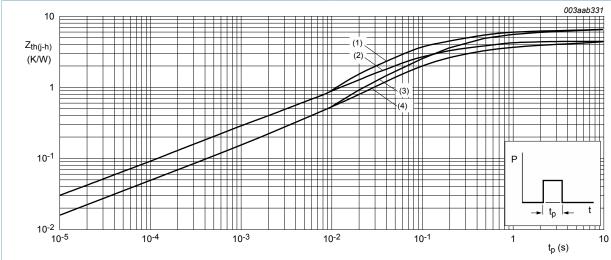


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8. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|---|-----|-----|-----|------|
| R _{th(j-h)} | thermal resistance from junction to | full or half cycle; without heatsink compound; Fig. 6 | - | - | 4.5 | K/W |
| | heatsink | full or half cycle; with heatsink compound; Fig. 6 | - | - | 6.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



- (1) Unidirectional (half cycle) without heatsink compound
- (2) Unidirectional (half cycle) with heatsink compound
- (3) Bidirectional (full cycle) without heatsink compound
- (4) Bidirectional (full cycle) with heatsink compound

Fig. 6. Transient thermal impedance from junction to heatsink as a function of pulse width

9. Isolation characteristics

Table 6. Isolation characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|-----------------------|--|-----|-----|------|------|
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink; f = 1 MHz; T _h = 25 °C | - | 10 | - | pF |

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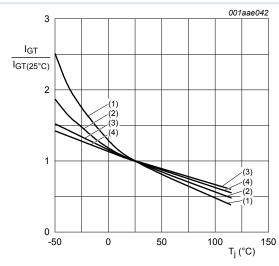
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10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|-----|------|------|
| Static char | acteristics | | ' | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ \text{ G-};$ $T_j = 25 ^{\circ}\text{C}; \underline{\text{Fig. 7}}$ | - | 8 | 35 | mA |
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2- \text{G-};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 7}}$ | - | 11 | 35 | mA |
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2- G+;$ $T_j = 25 \text{ °C}; Fig. 7$ | - | 30 | 70 | mA |
| I _L | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 30 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | 16 | 45 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 ^{\circ}\text{C}; \underline{\text{Fig. 8}}$ | - | 5 | 30 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 8}}$ | - | 7 | 45 | mA |
| lн | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 5 | 20 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.65 | V |
| √ _{GT} | gate trigger voltage | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic cl | haracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit | 100 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T_j = 95 °C; dI_{com}/dt = 3.6 A/ ms; I_T = 6 A; gate open circuit | - | 20 | - | V/µs |
| gt | gate-controlled turn-on time | I_{TM} = 12 A; V_D = 600 V; I_G = 0.1 A; $dI_G/$ dt = 5 A/ μ s | - | 2 | - | μs |
| | | | | | | |

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- (1) T2- G-
- (2) T2+ G-
- (3) T2+ G+
- (4) T2- G+

Fig. 7. Normalized gate trigger current as a function of junction temperature

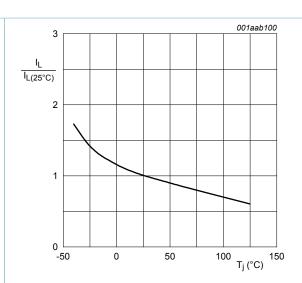


Fig. 8. Normalized latching current as a function of junction temperature

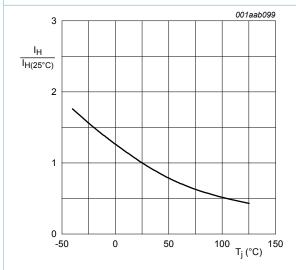
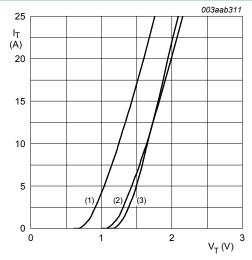


Fig. 9. Normalized holding current as a function of junction temperature



 $V_o = 1.26 \text{ V}; R_s = 0.0378 \Omega$

(1) T_i = 125 °C; typical values

(2) T_i = 125 °C; maximum values

(3) T_i = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

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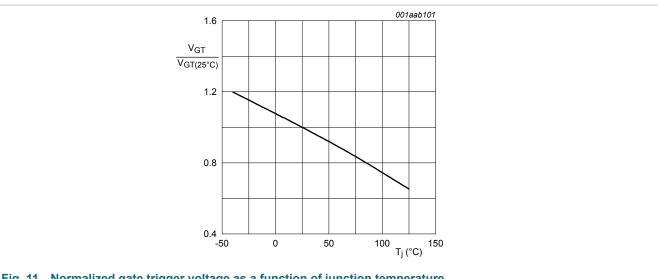


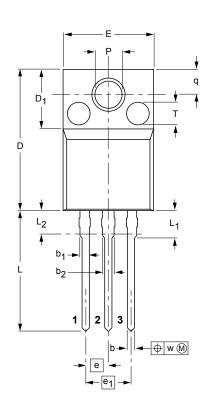
Fig. 11. Normalized gate trigger voltage as a function of junction temperature

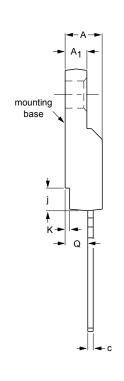
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11. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'

SOT186A





0 5 10 mm L.... scale

DIMENSIONS (mm are the original dimensions)

| UNIT | Α | A ₁ | b | b ₁ | b ₂ | С | D | D ₁ | E | е | e ₁ | j | к | L | L ₁ | L ₂ ⁽¹⁾ max. | Р | Q | q | T ⁽²⁾ | w |
|------|------------|----------------|------------|----------------|----------------|------------|--------------|----------------|-------------|------|----------------|------------|------------|--------------|----------------|---------------------------------------|------------|------------|------------|------------------|-----|
| mm | 4.6 4.0 | 2.9 2.5 | 0.9 0.7 | 1.1 0.9 | 1.4 1.0 | 0.7 0.4 | 15.8 15.2 | 6.5 6.3 | 10.3 9.7 | 2.54 | 5.08 | 2.7 1.7 | 0.6 0.4 | 14.4 13.5 | 3.30 2.79 | 3 | 3.2 3.0 | 2.6 2.3 | 3.0 2.6 | 2.5 | 0.4 |

Notes

- 1. Terminal dimensions within this zone are uncontrolled.
- 2. Both recesses are # 2.5×0.8 max. depth

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | |
|---------|-----|----------------|----------|------------|------------|----------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | 1330E DATE | |
| SOT186A | | 3-lead TO-220F | | | | -02-04-09 06-02-14 | |

Fig. 12. Package outline TO-220F (SOT186A)

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